## NSN 5961-00-794-9058

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-794-9058 **Inclosure Material:** Metal **Overall Length:** Between 0.120 inches and 0.130 inches **Overall Diameter:** Between 0.145 inches and 0.155 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Gallium arsenide Voltage Rating In Volts Per Characteristic: 6.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Special Features:** voltage; junction pattern arrangement: pn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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